	Type	L#	Hits	Search Text	DBs
1.	IS&R	L1	1434	(257/64-66,352,353).CCLS.	USPAT
2	BRS	L.6	1	((strained near2 silicon) and (finFET fin-FET fin adj FET) and (silicon-germanium silicon adj germanium SiGe Si-Ge) and (lattice near2 constant)).clm.	US-PGPUB

	Time Stamp	Comments	Error Definition	Erro rs
i 1	2006/01/03 07:35			
2	2006/01/03 12:19			